

Photoconductivity and Electronic Structures of CdCr₂Se₄

Katsuaki SATO and Teruo TERANISHI

Broadcasting Science Research Laboratories of Nippon Hosho Kyokai, Setagaya-ku, Tokyo

(Received May 26, 1970)

Recently Berger *et al.*¹⁾ and Wittekoek *et al.*²⁾ independently observed that the absorption edge of CdCr₂Se₄ was not the semiconductor band edge but rather consisting of several types of absorption such as those due to charge transfer and crystal-field transitions.

To get a further information about the origin of absorption edge of chalcogenide spinels, photoconductivity measurements were carried out on the single crystals of CdCr₂Se₄. Undoped *p*-type crystals with the resistivity of the order of 10⁸ ohm-cm were used for these measurements. Evaporated gold electrodes provided good ohmic contacts over the temperature range of measurements. Monochromatic light from a high-intensity spectrometer (Bausch-Lomb 33-86-03,

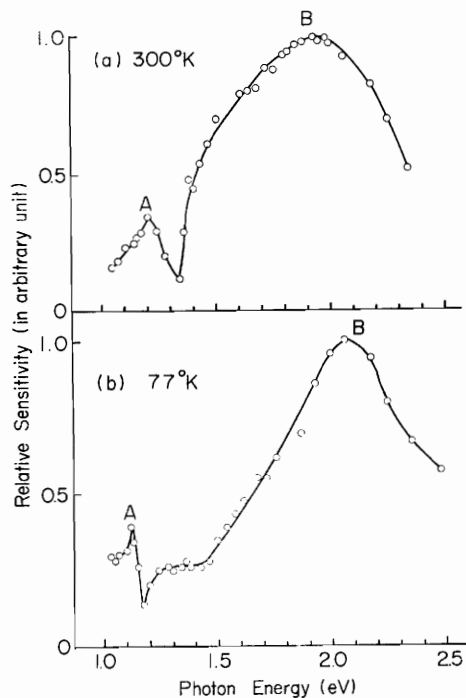


Fig. 1. Relative spectral sensitivity of the photocurrent, at 300°K (a) and 77°K (b).

07) was chopped at 480 Hz and the photocurrent was detected by a narrow-band phase sensitive detector.

The relative spectral sensitivity curves of the photocurrent are given in Fig. 1(a) and Fig. 1(b) for 300°K and 77°K, respectively. Two prominent peaks were observed, one at 1.25 eV (peak-A) and the other at 1.9 eV (peak-B) at room temperature. The peak-A is

narrower and weaker than peak-B. In Fig. 2 energy of the peak-A is plotted against temperature. Peak-A moves toward lower energy (red shift), while peak-B slightly toward higher energy (blue shift) as the temperature is decreased.

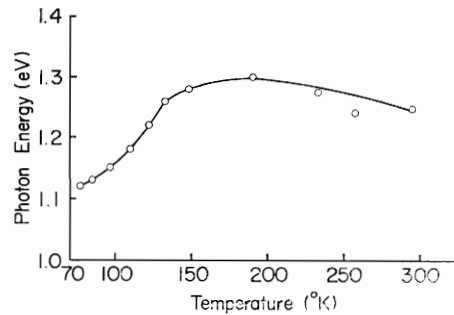


Fig. 2. Temperature shift of peak-A.

It is evident from these results that the peak-A is associated with the optical absorption edge reported by Harbeke *et al.*³⁾ The sharpness of this peak indicates that the corresponding transition is localized in character.

The broad and intense feature of the peak-B with its slight blue shift allows us to interpret this peak as originating from a direct band to band transition.

These interpretations are consistent with a preliminary measurement on the reflectivity spectrum of this material, which shows a prominent peak around 2 eV but not any such structure around 1.25 eV.

As the investigated samples were of *p*-type, negative magnetoresistance was not observed on the dark current, as was reported by Lehmann *et al.*⁴⁾ The photocurrent, however, showed this effect in the vicinity of the Curie temperature. This implies that the observed photocurrent is of electrons.

The authors are very grateful to Mr. Y. Kondo for his assistance.

References

- 1) S.B. Berger and L. Ekstrom: Phys. Rev. Letters **23** (1969) 1499.
- 2) S. Wittekoek and P.F. Bongers: Solid State Commun. **7** (1969) 1719.
- 3) G. Harbeke and H. Pinch: Phys. Rev. Letters **17** (1966) 1090.
- 4) H.W. Lehmann: Phys. Rev. **163** (1967) 488.